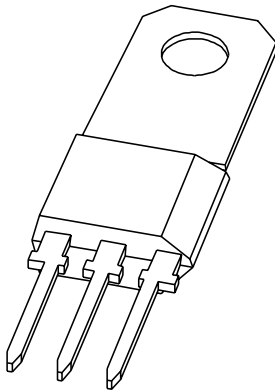


DATA SHEET



BD830 PNP power transistor

Product specification
Supersedes data of 1998 May 29

1999 Apr 21

PNP power transistor

BD830

FEATURES

- High current (max. 1 A)
- Low voltage (max. 80 V).

APPLICATIONS

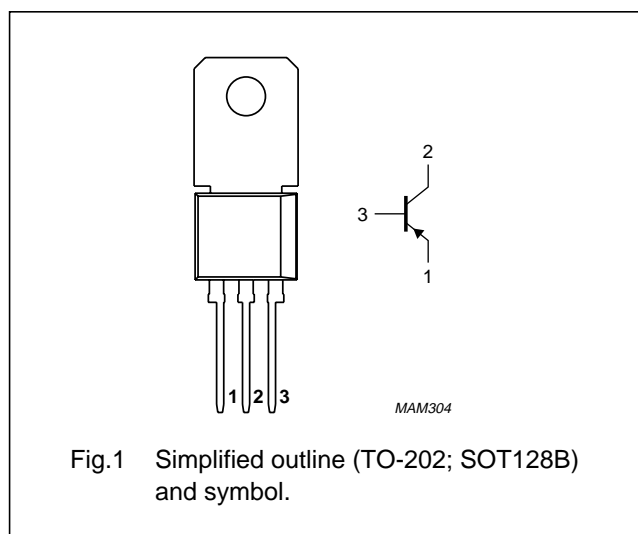
- General purpose
- Driver stages in hi-fi amplifiers and television circuits.

DESCRIPTION

PNP power transistor in a TO-202; SOT128B plastic package. NPN complement: BD829.

PINNING

PIN	DESCRIPTION
1	emitter
2	collector, connected to metal part of mounting surface
3	base



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	—	–100	V
V_{CEO}	collector-emitter voltage	open base	—	–80	V
V_{EBO}	emitter-base voltage	open collector	—	–5	V
I_C	collector current (DC)		—	–1	A
I_{CM}	peak collector current		—	–1.5	A
I_{BM}	peak base current		—	–500	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25\text{ °C}$	—	2	W
		$T_{mb} \leq 50\text{ °C}$	—	8	W
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		—	150	°C
T_{amb}	operating ambient temperature		–65	+150	°C

PNP power transistor

BD830

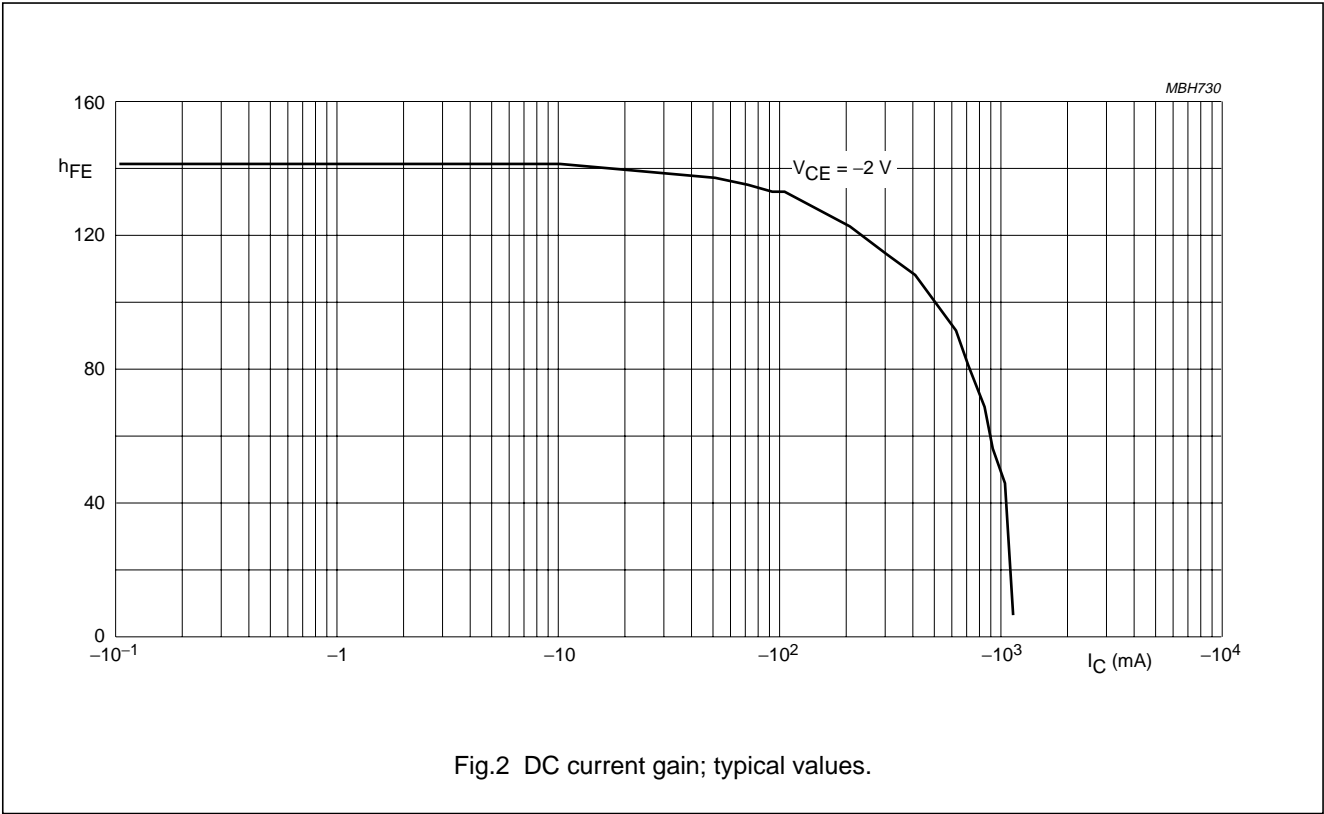
THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient	in free air	62.5	K/W
$R_{th\ j-mb}$	thermal resistance from junction to mounting base		12.5	K/W

CHARACTERISTICS

$T_j = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I_{CBO}	collector cut-off current	$I_E = 0; V_{CB} = -30\text{ V}$	–	–	–100	nA
		$I_E = 0; V_{CB} = -30\text{ V}; T_j = 125\text{ }^{\circ}\text{C}$	–	–	–10	μA
I_{EBO}	emitter cut-off current	$I_C = 0; V_{EB} = -5\text{ V}$	–	–	–100	nA
h_{FE}	DC current gain	$V_{CE} = -2\text{ V}$; see Fig.2				
		$I_C = -5\text{ mA}$	40	–	–	
		$I_C = -150\text{ mA}$	63	–	250	
		$I_C = -500\text{ mA}$	25	–	–	
V_{CEsat}	collector-emitter saturation voltage	$I_C = -500\text{ mA}; I_B = -50\text{ mA}$	–	–	–500	mV
V_{BE}	base-emitter voltage	$I_C = -500\text{ mA}; V_{CE} = -2\text{ V}$	–	–	–1	V
f_T	transition frequency	$I_C = -50\text{ mA}; V_{CE} = -5\text{ V}; f = 100\text{ MHz}$	–	75	–	MHz



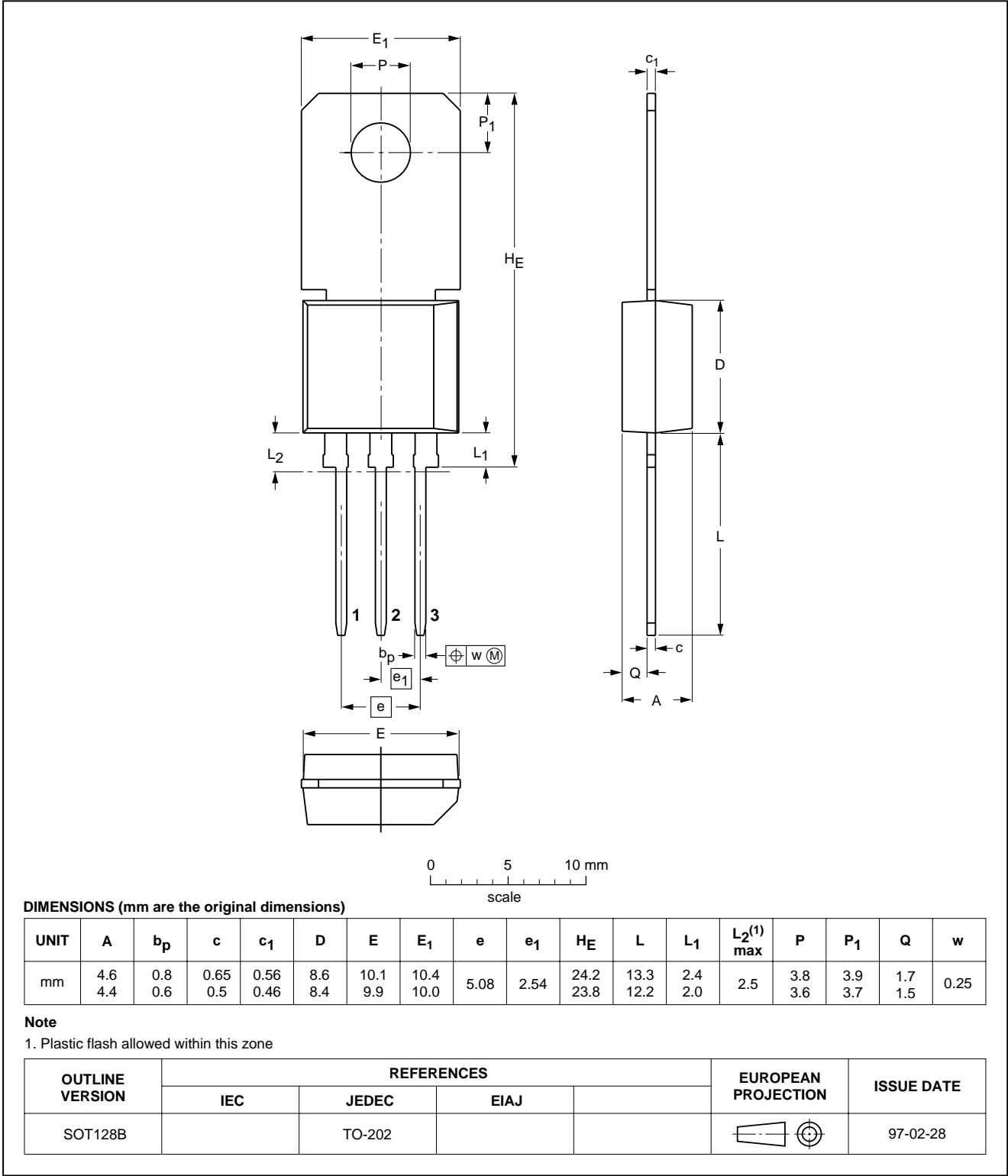
PNP power transistor

BD830

PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; with cooling fin, mountable to heatsink, 1 mounting hole; 3 leads (in-line)

SOT128B



PNP power transistor

BD830

DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

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PNP power transistor

BD830

NOTES

PNP power transistor

BD830

NOTES

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Printed in The Netherlands

115002/00/04/pp8

Date of release: 1999 Apr 21

Document order number: 9397 750 05688

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